

Laser Physics I (PHYC/ECE 464) FALL 2019

Final Exam, Closed Book, Closed Notes No computers, No cell-phones. Calculators will be provided Dec. 9, 2019, Time: 5:30 – 7:30 pm

NAME last first

Score		

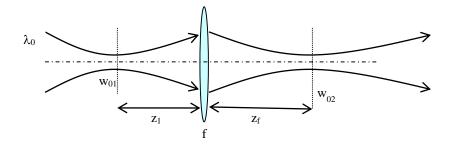
Total= 100

- Write your name on each sheet.
- Please staple and return these pages with your exam.



Instructor: M. Sheik-Bahae

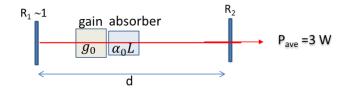
1. (30 points) A laser beam with wavelength λ_0 is incident from left on a lens with focal length **f** placed at a distance z_1 after its minimum waist, as shown below.



- (a) (15 pts.) What is the **q**-parameter, beam radius **w** and radius of curvature **R** at the following locations: a.1 Just before the lens?
 - a.2 Right after the lens?
 - a.3 At an arbitrary distance z_2 after the lens?

(b) (15 *pts.*) Show how to determine the location (z_f) and the value (w_{02}) of the new focus in terms of the given parameters.

2. (40 points) Consider the laser system below with an average CW output power of 3 Watts with an <u>optimized</u> output coupling (T_2^{opt}) when pumped at an integrated small-signal gain of $g_0=0.25$. The only internal loss is from an intracavity absorber with $\alpha_0 L=0.02$. All other intracavity surfaces are considered lossless (AR coated). The beam radius inside the cavity is w~80 µm inside the gain and absorber media.



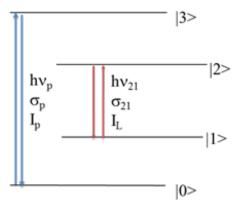
- (a) What is the output coupler reflectivity \mathbf{R}_2 ?
- (**b**) What are g_{th} and γ_0/γ_{th} ?
- (c) What is the *total intensity* inside the gain medium and the gain saturation intensity? (Assume and justify a high-Q cavity, and assume homogeneously broadened gain)
- (d) Estimate the total power absorbed in the absorber.

This laser may be CW mode-locked to generate a train of pulses with **100 MHz** repetition rate and a peak pulse power of $P_{peak} \sim 300 \text{ kW}$.

- (e) Estimate the pulsewidth Δt_p ?
- (f) What is the effective cavity length d (assume $n_g=1$)?
- (g) What is the saturation intensity of the absorber knowing that it saturates to 90% to its unsaturated value when the laser is mode-locked.
- (h) What *lifetime characteristics* render the gain and the saturable absorber suitable for modelocking?

3. (30 points)

(a) (10 pts.) Write the rate equations for this 4-level system assuming optical pumping from levels $0\rightarrow 3$ and laser action from levels $2\rightarrow 1$. Lifetimes τ_3 , τ_2 , τ_1 , and branching rations ϕ_{32} , ϕ_{31} , ϕ_{30} , ϕ_{21} , ϕ_{20} , and degeneracy factors g_0 , g_1 , g_2 , g_3 are known.



(b) (10 pts.) The above system is to be used as a laser amplifier. Assume $v_p=2v_{12}$, $\phi_{31}\sim\phi_{30}\sim\phi_{20}\sim0$, $\phi_{32}=0.8$, $\tau_1\sim0$. If 15W of pump power is absorbed, what is the maximum power that can be possibly extracted from this amplifier.

(c) (10 pts.) If $\lambda_{12}=1 \mu m$, $\tau_2=1 \mu s$, estimate the *total population* in level 2 for part 3-(b)

Formula Sheet

PHYC/ECE 464 (*Laser Physics I*)- University of New Mexico (2019) Instructor: Mansoor Sheik-Bahae



Hermite-Gaussian Beams

Hermite-Gaussian Deams						
$\frac{E(x, y, z)}{E_0} = H_m \left(\frac{\sqrt{2}x}{w(z)}\right) H_p$	$\left(\frac{\sqrt{2}y}{w(z)}\right)\frac{w_0}{w(z)}\exp\left(-i\frac{kr^2}{2q(z)}\right)\times\epsilon$	exp(-i[$kz - (1 + m + p) \tan^{-1}(z / z0) \Big] \Big)$			
$\frac{1}{q(z)} = \frac{1}{R(z)} - i \frac{\lambda_0}{\pi n w^2(z)},$	$w^{2}(z) = w_{0}^{2} \left(1 + \frac{z^{2}}{z_{0}^{2}} \right) , \qquad R(z)$	$z) = z \bigg(1 +$	$\left(\frac{z_0^2}{z^2}\right), \qquad z_0 = \frac{\pi n w_0^2}{\lambda_0} \qquad k$	$= n\frac{\omega}{c} = \frac{2\pi n}{\lambda_0}$		
Irradiance: $I = \langle S \rangle = \frac{nc\varepsilon_0}{2} E_0^2$		Snell's Law $n_i \sin(\theta_i) = n_t \sin(\theta_t)$				
Fresnel's reflectivities:		Intensity (Power) reflectivity: $R= r ^2$				
$r_{\parallel} = \frac{n_t \cos(\theta_i) - n_i \cos(\theta_i)}{n_t \cos(\theta_i) + n_i \cos(\theta_i)} = \frac{\tan(\theta_i - \theta_i)}{\tan(\theta_i + \theta_i)}$		Brewster angle (from 1 to 2): $\theta_B = \tan^{-1}(n_2 / n_1)$				
$n_i \cos(\sigma_i) + n_i \cos(\sigma_i) \tan(\sigma_i + \sigma_i)$			Critical angle (from 1 to 2): $\theta_c = \sin^{-1}(n_1 / n_2)$			
$r_{\perp} = -\frac{n_i \cos(\theta_i) - n_i \cos(\theta_i)}{n_i \cos(\theta_i) + n_i \cos(\theta_i)} = -\frac{\sin(\theta_i - \theta_i)}{\sin(\theta_i + \theta_i)}$		$n \rightarrow \tilde{n} = n + i\kappa$ in <i>n</i> complex				
$\sum_{i=1}^{\infty} n_i \cos(\theta_i) + n_t \cos(\theta_t)$	$\sin(\theta_i + \theta_i)$					
Lens Transformation of a Gaussian beam: $\frac{1}{R_{out}} = \frac{1}{R_{in}} - \frac{1}{f}$ $\frac{1}{f} = (n-1)\left(\frac{1}{R_1} - \frac{1}{R_2}\right)$ Lens-makers' formula:						
Fabry-Perot Transmiss	ion and Reflection (with	ı gain	or loss)			
		8				
$T(\theta, G_0) = \frac{G_0(1 - R_1)(1 - R_2)}{\left(1 - G_0\sqrt{R_1R_2}\right)^2 + 4G_0\sqrt{R_1R_2}\sin^2(\theta)}$			Finesse $F = \frac{\pi \sqrt[4]{R_1R_2}}{1 - \sqrt{R_2R_2}} = \frac{\Delta v_{FSR}}{\Delta v_{1/2}}$			
$R(\theta, G_0) = \frac{\left(\sqrt{R_1} - G_0\sqrt{R_2}\right)^2 + 4G_0\sqrt{R_1R_2}\sin^2(\theta)}{\left(1 - G_0\sqrt{R_2R_2}\right)^2 + 4G_0\sqrt{R_2R_2}\sin^2(\theta)}$			Free Spectral Range: $\Delta v_{FSR} = \frac{c}{2nd} = \frac{1}{\tau_{RT}}$			
$\left(1 - G_0 \sqrt{R_1 R_2}\right) + 4G_0 \sqrt{R_1 R_2} \sin^2(\theta)$			Photon Lifetime:			
$2\Delta\theta_{1/2} = \frac{1 - G_0 \sqrt{R_1 R_2}}{G_0^{1/2} \sqrt[4]{R_1 R_2}}$			$\tau_p = \frac{\tau_{RT}}{1 - R_1 R_2} \approx \frac{1}{2\pi \Delta \nu_{1/2}}$			
			General Resonance Condition:			
$\theta = kd = \frac{\omega nd}{c}$		roundtrip phase change = $q2\pi$				
ABCD Matrices $\begin{pmatrix} A & B \\ C & D \end{pmatrix}$	AD-BC=1	$ \begin{pmatrix} r_2 \\ r_2' \end{pmatrix} = \begin{pmatrix} \end{array} $	$ \begin{array}{c} A & B \\ C & D \end{array} \begin{pmatrix} r_1 \\ r_1' \end{pmatrix} $			
Free space of length d	Dielectric interface (from	ABCI	O rule for Gaussian	$q(z) = z + iz_0$		
$\begin{pmatrix} 1 & d \end{pmatrix}$	n_1 to n_2)	Beam	s	or		
		1	$Aq_1 + B$ I_1	1 1 λ_0		
· · ·	$\begin{pmatrix} 1 & 0 \\ 0 & n_1/n_2 \end{pmatrix}$		$\frac{Aq_1+B}{Cq_1+D}$ where	$\frac{1}{q(z)} = \frac{1}{R(z)} - i \frac{\lambda_0}{\pi n w(z)^2}$		
			ian pulse propagation (broade	ning) in dispersive		
		media				
immersed in vacuum $(n_1=1)$.	$\begin{pmatrix} 1 & 0 \\ -1/f & 1 \end{pmatrix}$	$\tau_p^2(z) = \tau_{p0}^2 \left(1 + \frac{z^2}{\ell_0^2} \right)$ where $\ell_0 = \frac{\tau_{p0}^2}{2 \beta_2 }$ and				
$\begin{pmatrix} n_1 - 1 \end{pmatrix}$. $\begin{pmatrix} 1 & d/n \end{pmatrix}$						
$ \begin{pmatrix} 1 & a/n \\ 0 & 1 \end{pmatrix} $ group velocity dispersion (GVD) $\beta_2 =$				$B_2 = \frac{\lambda^3}{2\pi c^2} \frac{d^2 n}{d\lambda^2} = \frac{\lambda^2}{2\pi c} D$		
Mirror with radius of	Mirror with radius of Spherical dielectric Photon		n Density (Photon Number per Volume)			
curvature R	vature R interface $N_p = I$					
	$\begin{pmatrix} 1 & 0 \end{pmatrix}$	$\overline{V} - \frac{1}{hvc/n_g}$				
$\begin{pmatrix} -2/R & 1 \end{pmatrix}$	interface $\begin{pmatrix} 1 & 0 \\ (1-n_1/n_2)/R & n_1/n_2 \end{pmatrix}$		~			

 $\begin{array}{ll} \text{Gain in a two-level system: } \gamma(v) = \sigma(v) \left[N_2 - \frac{g_2}{g_1} N_1 \right] & \text{Gain cross section: } \sigma(v) = A_{21} \frac{\lambda^2}{8\pi n^2} g(v) \\ \text{Lineshape Normalization: } \int g(v) dv = 1 & \text{Beer's Law: } \frac{1}{I} \frac{dI}{dz} = -\alpha(I) + \gamma(I) \\ \text{Gain or absorption saturation in a homogenously-broadened system:} \\ \gamma(I) = \frac{\gamma_0}{1 + I/I_s} & \text{or } \alpha(I) = \frac{\alpha_0}{1 + I/I_s} & I_s(v) = \frac{hv}{\sigma(v)\tau_2} \\ \text{Einstein's relation: } \frac{A_{21}}{B_{21}} = \frac{8\pi n^3 hv^3}{c^3} & g_2 B_{21} = g_1 B_{12} & \frac{N_2}{N_1} = \frac{g_2}{g_1} e^{-(E_2 - E_1)/kT} \\ \end{array}$

 $\frac{dN_p}{dt} = \frac{G^2 S - 1}{\tau_{RT}} N_p + N_2 c\sigma$ (Photon number dynamics due to *stimulated* and *spontaneous* emission)

S (survival factor)= R_1R_2 for a simple two mirror linear cavity, G^2 =roundtrip gain (exp($2\gamma L_g$)) Threshold condition: SG²=1 (linear cavity), SG=1 (ring cavity)

Schawlow-Townes limit for laser linewidth: $\Delta v_{osc} \approx 2\pi \frac{hv}{P_{out}} (\Delta v_{1/2})^2$

At steady-state: $\gamma = \gamma_{th} = \frac{\gamma_0}{1 + I/I_s}$ (for homogenously broadened)

Inside the gain medium: $I \approx I^+ + I^- \approx 2I^+$ for a high-Q linear (standing-wave) or bidirectional ring cavity, $I \approx I^+$ for a unidirectional ring cavity.

 $I_{out}=T_a..T_2I^+$ (T₂ is the output coupling transmission and $T_a...$ are the transmission of other optical surfaces in the path).

Optimum output coupling: $T_2^{opt} = -L_i + (g_0L_i)^{1/2}$ where L_i accounts for roundtrip internal (useless) losses, $g_0 = \gamma_0 l_g$ is the unsaturated (small signal) integrated gain. l_g is the length of the gain medium.

Q-Switching and Gain-Switching: $\Delta t_p \approx \tau_p$ (cavity photon lifetime)

Mode-locking: Repetition Rate = $1/T_{rt}=2Ln_g/c$ (linear cavity), Pulsewidth: $\Delta t_p \approx >1/\Delta v$

Threshold current density in a diode laser: $J_{th} = e N_{eh}{}^{th} d / \tau_r$

Physical Constants

$c=2.998 \times 10^8 \text{ m} \cdot \text{s}^{-1}$	h=6.63 $\times 10^{-34}$ J·s	$e=1.6 \times 10^{-19} C$
$k_B{=}1.380 \times 10^{-23} \; J{\cdot}K^{-1}$	$\epsilon_0 = 8.85 \times 10^{-12} \text{ F/m}$	$m_e = 9.1 \times 10^{-31} \text{ kg}$

 $1G = 10^{-4} T$, $1 eV = 1.602 \times 10^{-19} J$, $1 dyne = 10^{-5} N$, $1 erg = 10^{-7} J$